NSN 5962-01-420-9497

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N/a



View Online at https://aerobasegroup.com/nsn/5962-01-420-9497

Body Length:
0.358 inches
Body Width:
0.358 inches
Body Height:
0.075 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Pacer dawn
Features Provided:
Electrostatic sensitive and programmed and monolithic
Inclosure Configuration:
Leaded chip carrier
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Criticality Code Justification:
Cbbl
Case Outline Source And Designator:
C-2a mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, programmed (pal c16r4-20)
Voltage Rating And Type Per Characteristic:
5.0 volts power source
Time Rating Per Chacteristic:
20.00 nanoseconds input to output access
Memory Device Type:
Pal
Special Features:
Altered item, altered from p/n 5962-8871312xa, cage 67268, microcircuits, digital, cmos programmable logic array, monolithic silicon
Test Data Document:
96906-mil-std883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 gullwing
Shelf Life:

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Unit Of Measure:

Demilitarization:

No

Fiig:

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